DETAIL SPECIFICATION

Semiconductor Device, Triode Thyristor (Bi-Directional), Silicon, Types 2N5806 Through 2N5809

MIL-S-19500/438, dated 24 March 2004, remains inactive for new design; however, the document is valid for use.

Custodians: Army - CR  
Navy - EC  
Air Force - 85  
DLA - CC  

Preparing Activity: DLA - CC  

Reviewer Activities:  
Army - AR, AV, MI, SM  
Navy - AS, CG, MC, OS, SH  
Air Force - 19, 70, 99  
Other - NA  

NOTE: The activities above were interested in this document as of the date of this document. Since organizations and responsibilities can change, you should verify the currency of the information above using the ASSIST Online database at https://assist.daps.dla.mil.